







**PCF8574A** SCPS069G - JULY 2001 - REVISED AUGUST 2021

# PCF8574A Remote 8-Bit I/O Expander for I<sup>2</sup>C Bus

#### 1 Features

- Low standby-current consumption of 10 µA max
- I<sup>2</sup>C to parallel-port expander
- Open-drain interrupt output
- Compatible with most microcontrollers
- Latched outputs with high-current drive capability for directly driving LEDs
- Latch-up performance exceeds 100 mA Per JESD 78. Class II

# 2 Applications

- Telecom shelters: filter units
- Servers
- Routers (telecom switching equipment)
- Personal computers
- Personal electronics
- Industrial automation
- **Products with GPIO-Limited Processors**

# 3 Description

This 8-bit input/output (I/O) expander for the two-line bidirectional bus (I<sup>2</sup>C) is designed for 2.5-V to 6-V V<sub>CC</sub> operation.

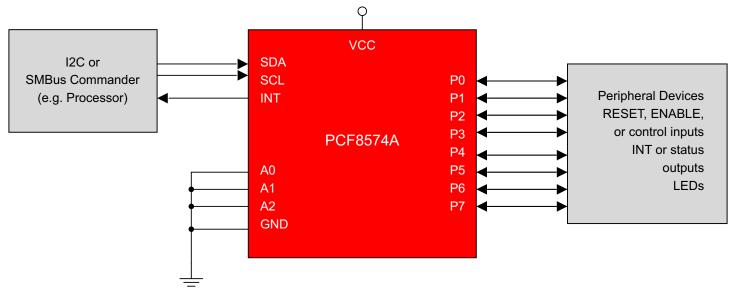
The PCF8574A device provides general-purpose remote I/O expansion for most microcontroller families via the I<sup>2</sup>C interface [serial clock (SCL), serial data (SDA)].

The device features an 8-bit quasi-bidirectional I/O port (P0-P7), including latched outputs with highcurrent drive capability for directly driving LEDs. Each quasi-bidirectional I/O can be used as an input or output without the use of a data-direction control signal. At power on, the I/Os are high. In this mode, only a current source to V<sub>CC</sub> is active.

#### **Device Information**

PART NUMBER	PACKAGE <sup>(1)</sup>	BODY SIZE (NOM)
	VQFN (20)	4.50 mm × 3.50 mm
	PDIP (16)	19.30 mm × 6.35 mm
PCF8574A	SOIC (16)	10.30 mm × 7.50 mm
	TSSOP (20)	6.50 mm × 4.40 mm
	TVSOP (20)	5.00 mm × 4.40 mm

For all available packages, see the orderable addendum at the end of the data sheet.





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4 Revision History Changes from Revision F (January 2015) t			Page
<ul> <li>Globally changed instances of legacy term</li> </ul>	ninology to	commander and responder where mentioned	1
<ul> <li>Changed Figure 7-2 Responder address f</li> </ul>	rom: S0100	) To: S0111	9
		figured as 0111000	
Changes from Revision E (January 2015) 1	to Revisior	ı F (January 2015)	Page
Added Junction temperature to the Absolu	ıte Maximu	m Ratings	4
		and $f_{SCL}$ = 400 kHz to $f_{SCL}$ = 100 kHz in Supply (	
		in Standby Supply Current vs Temperature	
		and $f_{SCL}$ = 400 kHz to $f_{SCL}$ = 100 kHz in Supply (	
	. ,		
vs Supply Vollage	•••••		/
Changes from Revision D (October 2005)	to Revision	F (January 2015)	Page
		1 = (Gariaary 2010)	

 Added Applications, Device Information table, Pin Functions table, ESD Ratings table, Thermal Information table, Typical Characteristics, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and



# **5 Pin Configuration and Functions**

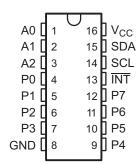


Figure 5-1. DW or N Package 16 Pins Top View

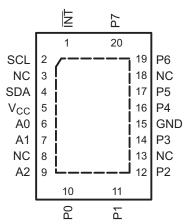


Figure 5-2. RGY Package 20 Pins Top View

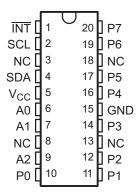


Figure 5-3. DGV or PW Package 20 Pins Top View

**Table 5-1. Pin Functions** 

	P	PIN		TYPE	DESCRIPTION
NAME	RGY	DGV or PW	DW or N	1176	DESCRIPTION
A[02]	6, 7, 9	6, 7, 9	1, 2, 3	ı	Address inputs 0 through 2. Connect directly to V <sub>CC</sub> or ground. Pullup resistors are not needed.
GND	15	15	8	_	Ground
ĪNT	1	1	13	0	Interrupt output. Connect to V <sub>CC</sub> through a pullup resistor.
NC	3, 8, 13, 18	3, 8, 13, 18	-	_	Do not connect
P[07]	10, 11, 12, 14, 16, 17, 19, 20	10, 11, 12, 14, 16, 17, 19, 20	4, 5, 6, 7, 9, 10, 11, 12	I/O	P-port input/output. Push-pull design structure.
SCL	2	2	14	ı	Serial clock line. Connect to V <sub>CC</sub> through a pullup resistor
SDA	4	4	15	I/O	Serial data line. Connect to V <sub>CC</sub> through a pullup resistor.
V <sub>CC</sub>	5	5	16	_	Voltage supply



# **6 Specifications**

# **6.1 Absolute Maximum Ratings**

over operating free-air temperature range (unless otherwise noted) (1)

		·	MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range	Supply voltage range			
V <sub>I</sub>	Input voltage range <sup>(2)</sup>		-0.5	V <sub>CC</sub> + 0.5	V
Vo	Output voltage range <sup>(2)</sup>		-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < 0		-20	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-20	mA
I <sub>OK</sub>	Input/output clamp current	$V_O < 0$ or $V_O > V_{CC}$		±400	μA
I <sub>OL</sub>	Continuous output low current	V <sub>O</sub> = 0 to V <sub>CC</sub>		50	mA
I <sub>OH</sub>	Continuous output high current	V <sub>O</sub> = 0 to V <sub>CC</sub>		-4	mA
	Continuous current through V <sub>CC</sub> or GND		±100	mA	
TJ	Junction temperature			150	°C
T <sub>stg</sub>	Storage temperature range		-65	150	°C

<sup>(1)</sup> Operation outside the *Absolute Maximum Ratings* may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under *Recommended Operating Conditions*. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

## 6.2 ESD Ratings

			VALUE	UNIT
		Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins <sup>(1)</sup>	1000	
V <sub>(ESD)</sub>	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins <sup>(2)</sup>	1500	V

<sup>(1)</sup> JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

### 6.3 Recommended Operating Conditions

		MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage	2.5	6	V
V <sub>IH</sub>	High-level input voltage	0.7 × V <sub>CC</sub>	V <sub>CC</sub> + 0.5	V
V <sub>IL</sub>	Low-level input voltage	-0.5	0.3 × V <sub>CC</sub>	V
I <sub>OH</sub>	High-level output current		-1	mA
I <sub>OL</sub>	Low-level output current		25	mA
T <sub>A</sub>	Operating free-air temperature	-40	85	°C

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<sup>(2)</sup> The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>(2)</sup> JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



# **6.4 Thermal Information**

			PCF8574					
	THERMAL METRIC(1)	DGV DW N PW RGY						
		20 PINS	16 PINS	16 PINS	20 PINS	20 PINS		
$R_{\theta JA}$	Junction-to-ambient thermal resistance	112.2	79.7	48.3	99.5	41.5	°C/W	
R <sub>0JC(top)</sub>	Junction-to-case (top) thermal resistance	35.2	42.5	35.6	34.5	42.5	°C/W	
$R_{\theta JB}$	Junction-to-board thermal resistance		44.4	28.2	50.5	16.9	°C/W	
ΨЈТ	Junction-to-top characterization parameter	1.8	14.8	20.5	2.0	0.8	°C/W	
ΨЈВ	Junction-to-board characterization parameter	52.8	43.8	28.1	49.9	16.8	°C/W	
R <sub>0JC(bot)</sub>	Junction-to-case (bottom) thermal resistance	n/a	n/a	n/a	n/a	5.9	°C/W	

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the Semiconductor and IC package thermal metrics application report.

### **6.5 Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP <sup>(1)</sup>	MAX	UNIT
V <sub>IK</sub>	Input diode clamp voltage	I <sub>I</sub> = -18 mA	2.5 V to 6 V	-1.2			V
V <sub>POR</sub>	Power-on reset voltage <sup>(2)</sup>	$V_I = V_{CC}$ or GND, $I_O = 0$	6 V		1.3	2.4	V
I <sub>OH</sub>	P port	V <sub>O</sub> = GND	2.5 V to 6 V	30		300	μA
I <sub>OHT</sub>	P-port transient pullup current	High during acknowledge, V <sub>OH</sub> = GND	2.5 V		-1		mA
	SDA	V <sub>O</sub> = 0.4 V	2.5 V to 6 V	3			
I <sub>OL</sub>	P port	V <sub>O</sub> = 1 V	5 V	10	25		mA
	INT	V <sub>O</sub> = 0.4 V	2.5 V to 6 V	1.6			
	SCL, SDA					±5	
I <sub>I</sub>	ĪNT	V <sub>I</sub> = V <sub>CC</sub> or GND	2.5 V to 6 V			±5	μΑ
	A0, A1, A2					±5	
I <sub>IHL</sub>	P port	$V_1 \ge V_{CC}$ or $V_1 \le GND$	2.5 V to 6 V			±400	μA
	Operating mode	$V_I = V_{CC}$ or GND, $I_O = 0$ , $f_{SCL} = 100$ kHz	61/		40	100	
I <sub>CC</sub>	Standby mode	$V_I = V_{CC}$ or GND, $I_O = 0$	6 V		2.5	10	μA
Ci	SCL	V <sub>I</sub> = V <sub>CC</sub> or GND	2.5 V to 6 V		1.5	7	pF
_	SDA	V = V = CND	251/4-61/		3	7	
C <sub>io</sub>	P port	$V_{IO} = V_{CC}$ or GND	2.5 V to 6 V		4	10	pF

<sup>(1)</sup> All typical values are at  $V_{CC} = 5 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

The power-on reset circuit resets the  $I^2$ C-bus logic with  $V_{CC} < V_{POR}$  and sets all I/Os to logic high (with current source to  $V_{CC}$ ).



# 6.6 I<sup>2</sup>C Interface Timing Requirements

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 7-1)

		,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	MIN	MAX	UNIT
f <sub>scl</sub>	I <sup>2</sup> C clock frequency			100	kHz
t <sub>sch</sub>	I <sup>2</sup> C clock high time		4		μs
t <sub>scl</sub>	I <sup>2</sup> C clock low time		4.7		μs
t <sub>sp</sub>	I <sup>2</sup> C spike time			100	ns
t <sub>sds</sub>	I <sup>2</sup> C serial-data setup time		250		ns
t <sub>sdh</sub>	I <sup>2</sup> C serial-data hold time				ns
t <sub>icr</sub>	I <sup>2</sup> C input rise time			1	μs
t <sub>icf</sub>	I <sup>2</sup> C input fall time			0.3	μs
t <sub>ocf</sub>	I <sup>2</sup> C output fall time (10-pF to 400-pF bus)			300	ns
t <sub>buf</sub>	I <sup>2</sup> C bus free time between stop and start		4.7		μs
t <sub>sts</sub>	I <sup>2</sup> C start or repeated start condition setup		4.7		μs
t <sub>sth</sub>	I <sup>2</sup> C start or repeated start condition hold		4		μs
t <sub>sps</sub>	I <sup>2</sup> C stop-condition setup		4		μs
t <sub>vd</sub>	Valid-data time	SCL low to SDA output valid		3.4	μs
C <sub>b</sub>	I <sup>2</sup> C bus capacitive load			400	pF

# **6.7 Switching Characteristics**

over recommended operating free-air temperature range,  $C_L \le 100 \text{ pF}$  (unless otherwise noted) (see Figure 7-2)

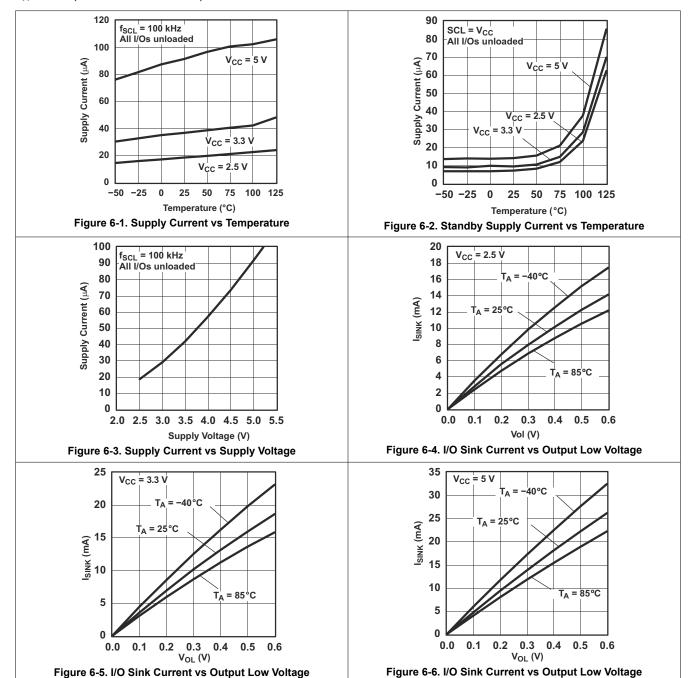
	PARAMETER	FROM (INPUT)	TO (OUTPUT)	MIN	MAX	UNIT
t <sub>pv</sub>	Output data valid	SCL	P port		4	μs
t <sub>su</sub>	Input data setup time	P port	SCL	0		μs
t <sub>h</sub>	Input data hold time	P port	SCL	4		μs
t <sub>iv</sub>	Interrupt valid time	P port	ĪNT		4	μs
t <sub>ir</sub>	Interrupt reset delay time	SCL	ĪNT		4	μs

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# **6.8 Typical Characteristics**

T<sub>A</sub> = 25°C (unless otherwise noted)





# **6.8 Typical Characteristics (continued)**

### T<sub>A</sub> = 25°C (unless otherwise noted)

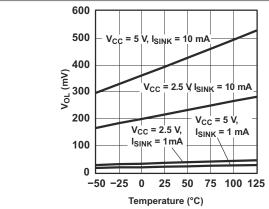


Figure 6-7. I/O Output Low Voltage vs Temperature

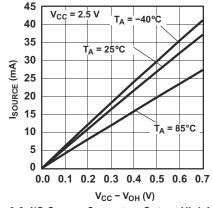


Figure 6-8. I/O Source Current vs Output High Voltage

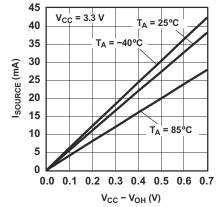


Figure 6-9. I/O Source Current vs Output High Voltage

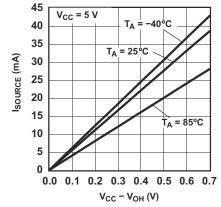


Figure 6-10. I/O Source Current vs Output High Voltage

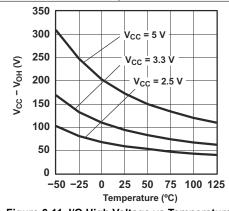
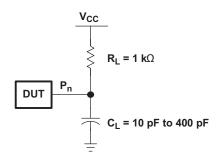


Figure 6-11. I/O High Voltage vs Temperature

### 7 Parameter Measurement Information



**LOAD CIRCUIT** 

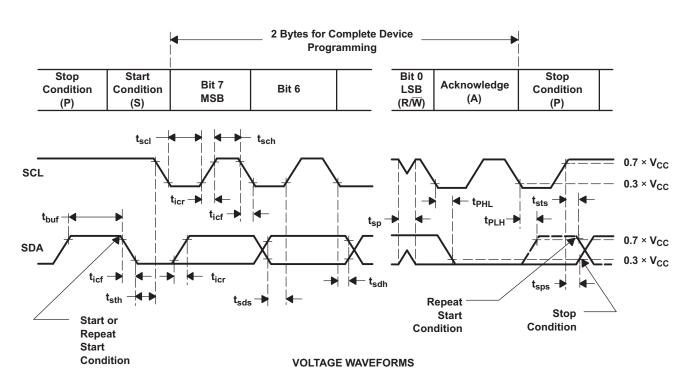


Figure 7-1. I<sup>2</sup>C Interface Load Circuit and Voltage Waveforms



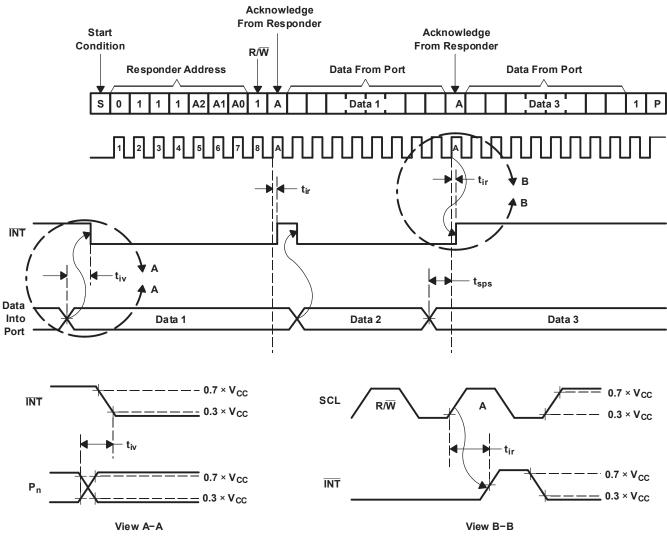


Figure 7-2. Interrupt Voltage Waveforms

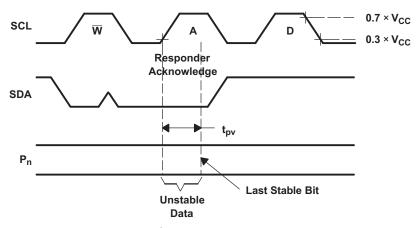


Figure 7-3. I<sup>2</sup>C Write Voltage Waveforms



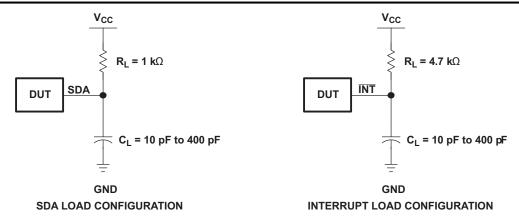


Figure 7-4. Load Circuits



# 8 Detailed Description

### 8.1 Overview

The PCF8574A device provides general-purpose remote I/O expansion for most microcontroller families via the I<sup>2</sup>C interface [serial clock (SCL), serial data (SDA)].

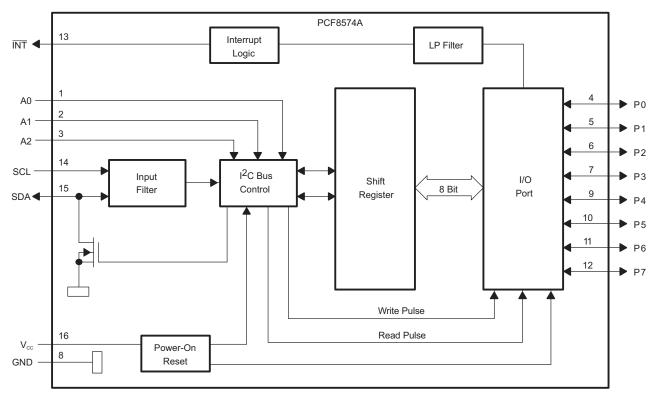
The device features an 8-bit quasi-bidirectional I/O port (P0–P7), including latched outputs with high-current drive capability for directly driving LEDs. Each quasi-bidirectional I/O can be used as an input or output without the use of a data-direction control signal. At power on, the I/Os are high. In this mode, only a current source to  $V_{CC}$  is active. An additional strong pullup to  $V_{CC}$  allows fast rising edges into heavily loaded outputs. This device turns on when an output is written high and is switched off by the negative edge of SCL. The I/Os should be high before being used as inputs.

The PCF8574A device provides an open-drain output ( $\overline{\text{INT}}$ ) that can be connected to the interrupt input of a microcontroller. An interrupt is generated by any rising or falling edge of the port inputs in the input mode. After time,  $t_{iv}$ ,  $\overline{\text{INT}}$  is valid. Resetting and reactivating the interrupt circuit is achieved when data on the port is changed to the original setting or data is read from, or written to, the port that generated the interrupt. Resetting occurs in the read mode at the acknowledge bit after the rising edge of the SCL signal, or in the write mode at the acknowledge bit after the high-to-low transition of the SCL signal. Interrupts that occur during the acknowledge clock pulse can be lost (or be very short) due to the resetting of the interrupt during this pulse. Each change of the I/Os after resetting is detected and, after the next rising clock edge, is transmitted as  $\overline{\text{INT}}$ . Reading from, or writing to, another device does not affect the interrupt circuit.

By sending an interrupt signal on this line, the remote I/O can inform the microcontroller if there is incoming data on its ports without having to communicate via the I<sup>2</sup>C bus. Therefore, the PCF8574A device can remain a simple responder device.

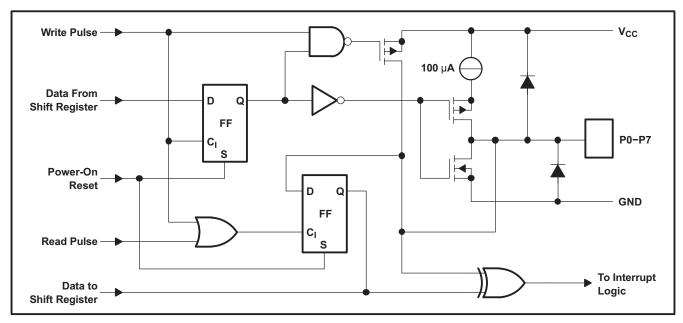
# 8.2 Functional Block Diagram

#### 8.2.1 Simplified Block Diagram of Device



Pin numbers shown are for the DW and N packages.

### 8.2.2 Simplified Schematic Diagram of Each P-Port Input/Output



## 8.3 Feature Description

#### 8.3.1 I<sup>2</sup>C Interface

 $I^2C$  communication with this device is initiated by a commander sending a start condition, a high-to-low transition on the SDA I/O while the SCL input is high. After the start condition, the device address byte is sent, most-significant bit (MSB) first, including the data direction bit (R/ $\overline{W}$ ). This device does not respond to the general call address. After receiving the valid address byte, this device responds with an acknowledge, a low on the SDA I/O during the high of the acknowledge-related clock pulse. The address inputs (A0–A2) of the responder device must not be changed between the start and the stop conditions.

The data byte follows the address acknowledge. If the R/  $\overline{W}$  bit is high, the data from this device are the values read from the P port. If the R/  $\overline{W}$  bit is low, the data are from the commander, to be output to the P port. The data byte is followed by an acknowledge sent from this device. If other data bytes are sent from the commander, following the acknowledge, they are ignored by this device. Data are output only if complete bytes are received and acknowledged. The output data will be valid at time,  $t_{pv}$ , after the low-to-high transition of SCL and during the clock cycle for the acknowledge.

A stop condition, a low-to-high transition on the SDA I/O while the SCL input is high, is sent by the commander.

#### 8.3.2 Interface Definition

ВУТЕ				В	IT			
BIIE	7 (MSB)	6	5	4	3	2	1	0 (LSB)
I <sup>2</sup> C responder address	L	Н	Н	Н	A2	A1	A0	R/W
I/O data bus	P7	P6	P5	P4	P3	P2	P1	P0



#### 8.3.3 Address Reference

II	NPUT	S	I <sup>2</sup> C BUS responder 8-BIT	I <sup>2</sup> C BUS responder
A2	<b>A</b> 1	A0	READ ADDRESS	8-BIT WRITE ADDRESS
L	L	L	113 (dec), 71 (hex)	112 (dec), 70 (hex)
L	L	Н	115 (dec), 73 (hex)	114 (dec), 72 (hex)
L	Н	L	117 (dec), 75 (hex)	116 (dec), 74 (hex)
L	Н	Н	119 (dec), 77 (hex)	118 (dec), 76 (hex)
Н	L	L	121 (dec), 79 (hex)	120 (dec), 78 (hex)
Н	L	Н	123 (dec), 7B (hex)	122 (dec), 7A (hex)
Н	Н	L	125 (dec), 7D (hex)	124 (dec), 7C (hex)
Н	Н	Н	127 (dec), 7F (hex)	126 (dec), 7E (hex)

### **8.4 Device Functional Modes**

Figure 8-1 and Figure 8-2 show the address and timing diagrams for the write and read modes, respectively.

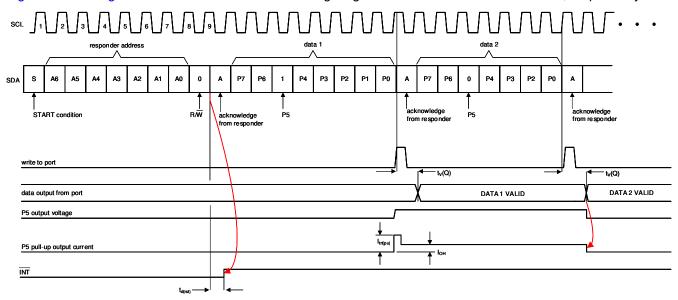
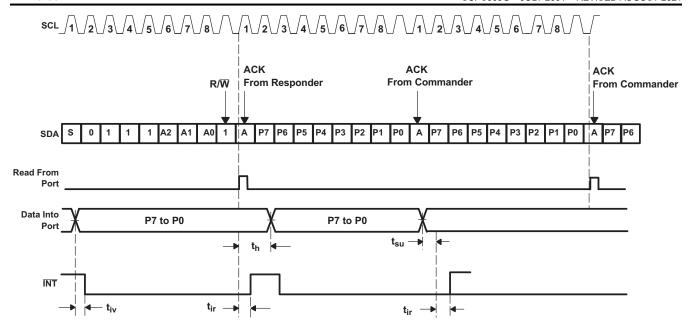


Figure 8-1. Write Mode (Output)



A. A low-to-high transition of SDA while SCL is high is defined as the stop condition (P). The transfer of data can be stopped at any moment by a stop condition. When this occurs, data present at the latest ACK phase is valid (output mode). Input data is lost.

Figure 8-2. Read Mode (Input)



# 9 Application Information Disclaimer

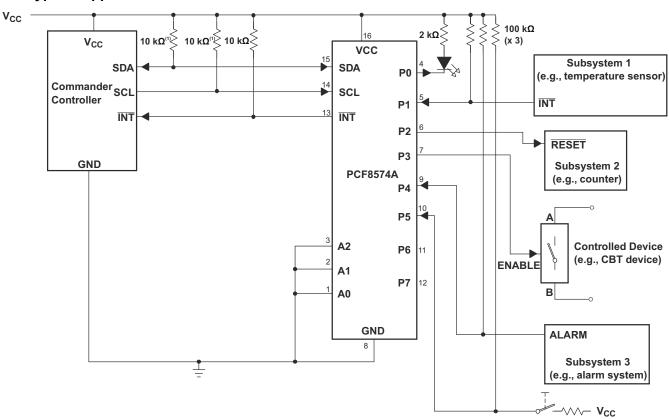
#### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

### 9.1 Application Information

Figure 9-1 shows an application in which the PCF8574A device can be used.

### 9.2 Typical Application



- A. The SCL and SDA pins must be pulled up to  $V_{CC}$  because if SCL and SDA are pulled up to an auxiliary power supply that could be powered on while  $V_{CC}$  is powered off, then the supply current,  $I_{CC}$ , will increase as a result.
- B. Device address is configured as 0111000 for this example.
- C. P0, P2, and P3 are configured as outputs.
- D. P1, P4, and P5 are configured as inputs.
- E. P6 and P7 are not used and must be configured as outputs.

Figure 9-1. Application Schematic



### 9.2.1 Design Requirements

### 9.2.1.1 Minimizing I<sub>CC</sub> When I/Os Control LEDs

When the I/Os are used to control LEDs, normally they are connected to  $V_{CC}$  through a resistor as shown in Figure 11-1. For a P-port configured as an input,  $I_{CC}$  increases as  $V_I$  becomes lower than  $V_{CC}$ . The LED is a diode, with threshold voltage  $V_T$ , and when a P-port is configured as an input the LED will be off but  $V_I$  is a  $V_T$  drop below  $V_{CC}$ .

For battery-powered applications, it is essential that the voltage of P-ports controlling LEDs is greater than or equal to  $V_{CC}$  when the P-ports are configured as input to minimize current consumption. Figure 9-2 shows a high-value resistor in parallel with the LED. Figure 9-3 shows  $V_{CC}$  less than the LED supply voltage by at least  $V_T$ . Both of these methods maintain the I/O  $V_I$  at or above  $V_{CC}$  and prevents additional supply current consumption when the P-port is configured as an input and the LED is off.

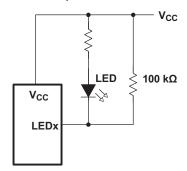


Figure 9-2. High-Value Resistor in Parallel With LED

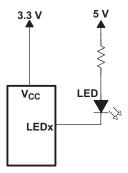


Figure 9-3. Device Supplied by a Lower Voltage



#### 9.2.2 Detailed Design Procedure

The pull-up resistors,  $R_P$ , for the SCL and SDA lines need to be selected appropriately and take into consideration the total capacitance of all responders on the  $I^2C$  bus. The minimum pull-up resistance is a function of  $V_{CC}$ ,  $V_{OL.(max)}$ , and  $I_{OL}$ :

$$R_{p(min)} = \frac{V_{CC} - V_{OL(max)}}{I_{OL}}$$
(1)

The maximum pull-up resistance is a function of the maximum rise time,  $t_r$  (300 ns for fast-mode operation,  $f_{SCL}$  = 400 kHz) and bus capacitance,  $C_b$ :

$$R_{p(max)} = \frac{t_r}{0.8473 \times C_b} \tag{2}$$

The maximum bus capacitance for an  $I^2C$  bus must not exceed 400 pF for standard-mode or fast-mode operation. The bus capacitance can be approximated by adding the capacitance of the PCF8574A device,  $C_i$  for SCL or  $C_{io}$  for SDA, the capacitance of wires/connections/traces, and the capacitance of additional responders on the bus.

# 9.2.3 Application Curves

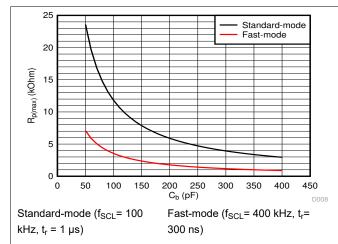
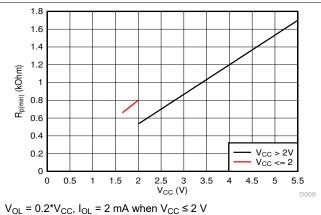


Figure 9-4. Maximum Pull-Up Resistance  $(R_{p(max)})$  vs Bus Capacitance  $(C_h)$ 



 $V_{OL} = 0.4 \text{ V}$ ,  $I_{OL} = 3 \text{ mA when } V_{CC} > 2 \text{ V}$ 

Figure 9-5. Minimum Pull-Up Resistance ( $R_{p(min)}$ ) vs Pull-Up Reference Voltage ( $V_{CC}$ )

# 10 Power Supply Recommendations

# 10.1 Power-On Reset Requirements

In the event of a glitch or data corruption, PCF8574A can be reset to its default conditions by using the power-on reset feature. Power-on reset requires that the device go through a power cycle to be completely reset. This reset also happens when the device is powered on for the first time in an application.

The two types of power-on reset are shown in Figure 10-1 and Figure 10-2.

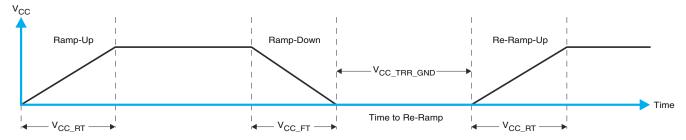


Figure 10-1.  $V_{CC}$  is Lowered Below 0.2 V or 0 V and Then Ramped Up to  $V_{CC}$ 

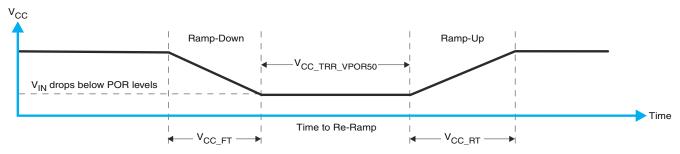


Figure 10-2. V<sub>CC</sub> is Lowered Below the POR Threshold, Then Ramped Back Up to V<sub>CC</sub>

Table 10-1 specifies the performance of the power-on reset feature for PCF8574A for both types of power-on reset.

rabio to in recommended capping coquencing and ramp rates										
	MIN	TYP	MAX	UNIT						
V <sub>CC_FT</sub>	Fall rate	See Figure 10-1	1		100	ms				
V <sub>CC_RT</sub>	Rise rate	See Figure 10-1	0.01		100	ms				
V <sub>CC_TRR_GND</sub>	Time to re-ramp (when V <sub>CC</sub> drops to GND)	See Figure 10-1	0.001			ms				
V <sub>CC_TRR_POR50</sub>	Time to re-ramp (when V <sub>CC</sub> drops to V <sub>POR_MIN</sub> – 50 mV)	See Figure 10-2	0.001			ms				
V <sub>CC_GH</sub>	Level that $V_{CCP}$ can glitch down to, but not cause a functional disruption when $V_{CCX\_GW}$ = 1 $\mu s$	See Figure 10-3			1.2	V				
V <sub>CC_GW</sub>	Glitch width that will not cause a functional disruption when $V_{CCX\_GH} = 0.5 \times V_{CCx}$	See Figure 10-3				μs				
V <sub>PORF</sub>	Voltage trip point of POR on falling V <sub>CC</sub>		0.767		1.144	V				
V <sub>PORR</sub>	Voltage trip point of POR on fising V <sub>CC</sub>		1.033		1.428	V				

Table 10-1. Recommended Supply Sequencing and Ramp Rates<sup>(1)</sup>

# (1) $T_A = -40$ °C to 85°C (unless otherwise noted)

Glitches in the power supply can also affect the power-on reset performance of this device. The glitch width  $(V_{CC\_GW})$  and height  $(V_{CC\_GH})$  are dependent on each other. The bypass capacitance, source impedance, and device impedance are factors that affect power-on reset performance. Figure 10-3 and Table 10-1 provide more information on how to measure these specifications.



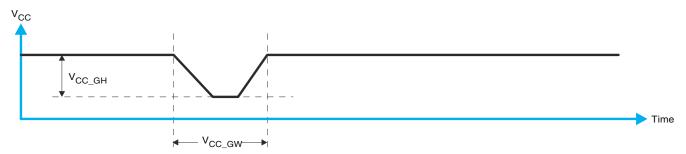
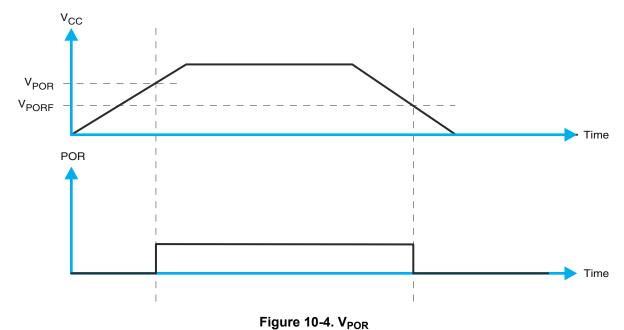


Figure 10-3. Glitch Width and Glitch Height

 $V_{POR}$  is critical to the power-on reset.  $V_{POR}$  is the voltage level at which the reset condition is released and all the registers and the I<sup>2</sup>C/SMBus state machine are initialized to their default states. The value of  $V_{POR}$  differs based on the  $V_{CC}$  being lowered to or from 0. Figure 10-4 and Table 10-1 provide more details on this specification.



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# 11 Layout

### 11.1 Layout Guidelines

For printed circuit board (PCB) layout of PCF8574A, common PCB layout practices should be followed but additional concerns related to high-speed data transfer such as matched impedances and differential pairs are not a concern for I2C signal speeds.

In all PCB layouts, it is a best practice to avoid right angles in signal traces, to fan out signal traces away from each other upon leaving the vicinity of an integrated circuit (IC), and to use thicker trace widths to carry higher amounts of current that commonly pass through power and ground traces. By-pass and de-coupling capacitors are commonly used to control the voltage on the  $V_{CC}$  pin, using a larger capacitor to provide additional power in the event of a short power supply glitch and a smaller capacitor to filter out high-frequency ripple. These capacitors should be placed as close to the PCF8574A device as possible. These best practices are shown in Figure 11-1.

For the layout example provided in Figure 11-1, it would be possible to fabricate a PCB with only 2 layers by using the top layer for signal routing and the bottom layer as a split plane for power (V<sub>CC</sub>) and ground (GND). However, a 4 layer board is preferable for boards with higher density signal routing. On a 4 layer PCB, it is common to route signals on the top and bottom layer, dedicate one internal layer to a ground plane, and dedicate the other internal layer to a power plane. In a board layout using planes or split planes for power and ground, vias are placed directly next to the surface mount component pad which needs to attach to VCC or GND and the via is connected electrically to the internal layer or the other side of the board. Vias are also used when a signal trace needs to be routed to the opposite side of the board, but this technique is not demonstrated in Figure 11-1.

### 11.2 Layout Example

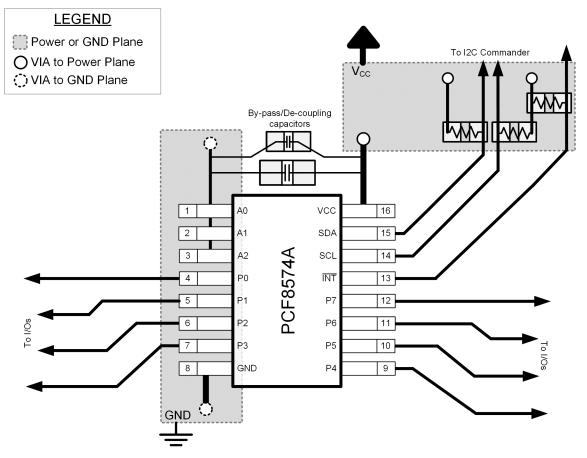


Figure 11-1. Layout Example for PCF8574A



# 12 Device and Documentation Support

# 12.1 Documentation Support

## 12.1.1 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms and definitions.

## 12.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

## 12.3 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

#### 12.4 Trademarks

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### 12.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 12.6 Glossary

TI Glossarv

This glossary lists and explains terms, acronyms, and definitions.

# 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser based versions of this data sheet, refer to the left hand navigation.

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#### PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
PCF8574ADWR	ACTIVE	SOIC	DW	16	2000	RoHS & Green	(6) NIPDAU	Level-1-260C-UNLIM	-40 to 85	PCF8574A	Samples
PCF8574AN	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	PCF8574AN	Samples
PCF8574ANE4	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	PCF8574AN	Samples
PCF8574APWR	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	PF574A	Samples
PCF8574APWRE4	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	PF574A	Samples
PCF8574APWRG4	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	PF574A	Samples
PCF8574ARGYR	ACTIVE	VQFN	RGY	20	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	PF574A	Samples

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.



# **PACKAGE OPTION ADDENDUM**

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(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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# **PACKAGE MATERIALS INFORMATION**

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### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
PCF8574ADWR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1
PCF8574APWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
PCF8574ARGYR	VQFN	RGY	20	3000	330.0	12.4	3.8	4.8	1.6	8.0	12.0	Q1

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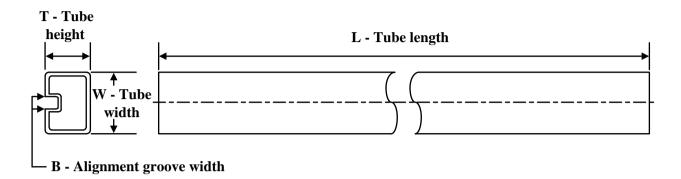
### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
PCF8574ADWR	SOIC	DW	16	2000	350.0	350.0	43.0
PCF8574APWR	TSSOP	PW	20	2000	356.0	356.0	35.0
PCF8574ARGYR	VQFN	RGY	20	3000	356.0	356.0	35.0

# **PACKAGE MATERIALS INFORMATION**

www.ti.com 9-Nov-2023

### **TUBE**



\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
PCF8574AN	N	PDIP	16	25	506	13.97	11230	4.32
PCF8574ANE4	N	PDIP	16	25	506	13.97	11230	4.32



SMALL OUTLINE PACKAGE



#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



# PW (R-PDSO-G20)

# PLASTIC SMALL OUTLINE



NOTES:

- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
  C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



3.5 x 4.5, 0.5 mm pitch

PLASTIC QUAD FGLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





PLASTIC QUAD FLATPACK - NO LEAD



#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
  2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



7.5 x 10.3, 1.27 mm pitch

SMALL OUTLINE INTEGRATED CIRCUIT

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





SOIC



#### NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing
- per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.
- 5. Reference JEDEC registration MS-013.



SOIC



### NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



#### NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



# N (R-PDIP-T\*\*)

# PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



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